

Small Signal Zener Diodes



FEATURES

- Very sharp reverse characteristic
- Low reverse current level
- Very high stability
- Low noise
- AEC-Q101 qualified
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC


RoHS
COMPLIANT

APPLICATIONS

- Voltage stabilization

PRIMARY CHARACTERISTICS		
PARAMETER	VALUE	UNIT
V _Z range nom.	2.4 to 75	V
Test current I _{ZT}	2.5 to 5	mA
V _Z specification	Pulse current	
Int. construction	Single	

ORDERING INFORMATION			
DEVICE NAME	ORDERING CODE	TAPED UNITS PER REEL	MINIMUM ORDER QUANTITY
BZT55-series	BZT55-series-GS18	10 000 per 13" reel	10 000/box
BZT55-series	BZT55-series-GS08	2500 per 7" reel	12 500/box

PACKAGE				
PACKAGE NAME	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS
QuadroMELF SOD-80	34 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Power dissipation	R _{thJA} ≤ 300 K/W	P _{tot}	500	mW
Zener current		I _Z	P _V /V _Z	mA
Junction to ambient air	On PC board 50 mm x 50 mm x 1.6 mm	R _{thJA}	500	K/W
Junction temperature		T _j	175	°C
Storage temperature range		T _{stg}	- 65 to + 175	°C
Forward voltage (max.)	I _F = 200 mA	V _F	1.5	V



ELECTRICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)												
PART NUMBER	ZENER VOLTAGE RANGE ⁽¹⁾			TEST CURRENT		REVERSE LEAKAGE CURRENT			DYNAMIC RESISTANCE		TEMPERATURE COEFFICIENT	
	V_z at I_{ZT1}			I_{ZT1}	I_{ZT2}	I_R at V_R			Z_z at I_{ZT1}	Z_{ZK} at I_{ZT2}	TK _{VZ}	
	V			mA		μA		V	Ω			
	MIN.	NOM.	MAX.						MAX.	MAX.	MIN.	MAX.
BZT55C2V4	2.28	2.4	2.56	5	1	< 50	< 100	1	< 85	< 600	- 0.09	- 0.06
BZT55C2V7	2.5	2.7	2.9	5	1	< 10	< 50	1	< 85	< 600	- 0.09	- 0.06
BZT55C3V0	2.8	3.0	3.2	5	1	< 4	< 40	1	< 90	< 600	- 0.08	- 0.05
BZT55C3V3	3.1	3.3	3.5	5	1	< 2	< 40	1	< 90	< 600	- 0.08	- 0.05
BZT55C3V6	3.4	3.6	3.8	5	1	< 2	< 40	1	< 90	< 600	- 0.08	- 0.05
BZT55C3V9	3.7	3.9	4.1	5	1	< 2	< 40	1	< 90	< 600	- 0.08	- 0.05
BZT55C4V3	4	4.3	4.6	5	1	< 1	< 20	1	< 90	< 600	- 0.06	- 0.03
BZT55C4V7	4.4	4.7	5	5	1	< 0.5	< 10	1	< 80	< 600	- 0.05	0.02
BZT55C5V1	4.8	5.1	5.4	5	1	< 0.1	< 2	1	< 60	< 550	- 0.02	0.02
BZT55C5V6	5.2	5.6	6	5	1	< 0.1	< 2	1	< 40	< 450	- 0.05	0.05
BZT55C6V2	5.8	6.2	6.6	5	1	< 0.1	< 2	2	< 10	< 200	0.03	0.06
BZT55C6V8	6.4	6.8	7.2	5	1	< 0.1	< 2	3	< 8	< 150	0.03	0.07
BZT55C7V5	7	7.5	7.9	5	1	< 0.1	< 2	5	< 7	< 50	0.03	0.07
BZT55C8V2	7.7	8.2	8.7	5	1	< 0.1	< 2	6.2	< 7	< 50	0.03	0.08
BZT55C9V1	8.5	9.1	9.6	5	1	< 0.1	< 2	6.8	< 10	< 50	0.03	0.09
BZT55C10	9.4	10	10.6	5	1	< 0.1	< 2	7.5	< 15	< 70	0.03	0.1
BZT55C11	10.4	11	11.6	5	1	< 0.1	< 2	8.2	< 20	< 70	0.03	0.11
BZT55C12	11.4	12	12.7	5	1	< 0.1	< 2	9.1	< 20	< 90	0.03	0.11
BZT55C13	12.4	13	14.1	5	1	< 0.1	< 2	10	< 26	< 110	0.03	0.11
BZT55C15	13.8	15	15.6	5	1	< 0.1	< 2	11	< 30	< 110	0.03	0.11
BZT55C16	15.3	16	17.1	5	1	< 0.1	< 2	12	< 40	< 170	0.03	0.11
BZT55C18	16.8	18	19.1	5	1	< 0.1	< 2	13	< 50	< 170	0.03	0.11
BZT55C20	18.8	20	21.2	5	1	< 0.1	< 2	15	< 55	< 220	0.03	0.11
BZT55C22	20.8	22	23.3	5	1	< 0.1	< 2	16	< 55	< 220	0.04	0.12
BZT55C24	22.8	24	25.6	5	1	< 0.1	< 2	18	< 80	< 220	0.04	0.12
BZT55C27	25.1	27	28.9	5	1	< 0.1	< 2	20	< 80	< 220	0.04	0.12
BZT55C30	28	30	32	5	1	< 0.1	< 2	22	< 80	< 220	0.04	0.12
BZT55C33	31	33	35	5	1	< 0.1	< 2	24	< 80	< 220	0.04	0.12
BZT55C36	34	36	38	5	1	< 0.1	< 2	27	< 80	< 220	0.04	0.12
BZT55C39	37	39	41	2.5	0.5	< 0.1	< 5	30	< 90	< 500	0.04	0.12
BZT55C43	40	43	46	2.5	0.5	< 0.1	< 5	33	< 90	< 600	0.04	0.12
BZT55C47	44	47	50	2.5	0.5	< 0.1	< 5	36	< 110	< 700	0.04	0.12
BZT55C51	48	51	54	2.5	0.5	< 0.1	< 10	39	< 125	< 700	0.04	0.12
BZT55C56	52	56	60	2.5	0.5	< 0.1	< 10	43	< 135	< 1000	0.04	0.12
BZT55C62	58	62	66	2.5	0.5	< 0.1	< 10	47	< 150	< 1000	0.04	0.12
BZT55C68	64	68	72	2.5	0.5	< 0.1	< 10	51	< 200	< 1000	0.04	0.12
BZT55C75	70	75	79	2.5	0.5	< 0.1	< 10	56	< 250	< 1500	0.04	0.12

Notes

- Additional measurement of voltage group 9V1 to 75 at 95 % $V_{zmin.} \leq 35\text{ nA}$ at $T_j 25\text{ }^{\circ}\text{C}$
- ⁽¹⁾ $t_p \leq 10\text{ ms}$, $T/t_p > 1000$



ELECTRICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)												
PART NUMBER	ZENER VOLTAGE RANGE ⁽¹⁾			TEST CURRENT		REVERSE LEAKAGE CURRENT			DYNAMIC RESISTANCE		TEMPERATURE COEFFICIENT	
	V_z at I_{ZT1}			I_{ZT1}	I_{ZT2}	I_R at V_R			Z_z at I_{ZT1}	Z_{zk} at I_{ZT2}	TK_{Vz}	
	V			mA		$T_{amb} = 25\text{ }^{\circ}\text{C}$		$T_{amb} = 150\text{ }^{\circ}\text{C}$	f = 1 kHz			
	MIN.	NOM.	MAX.			μA		V	Ω		MIN.	MAX.
BZT55B2V4	2.35	2.4	2.45	5	1	< 50	< 100	1	< 85	< 600	- 0.09	- 0.06
BZT55B2V7	2.64	2.7	2.76	5	1	< 10	< 50	1	< 85	< 600	- 0.09	- 0.06
BZT55B3V0	2.94	3.0	3.06	5	1	< 4	< 40	1	< 90	< 600	- 0.08	- 0.05
BZT55B3V3	3.24	3.3	3.36	5	1	< 2	< 40	1	< 90	< 600	- 0.08	- 0.05
BZT55B3V6	3.52	3.6	3.68	5	1	< 2	< 40	1	< 90	< 600	- 0.08	- 0.05
BZT55B3V9	3.82	3.9	3.98	5	1	< 2	< 40	1	< 90	< 600	- 0.08	- 0.05
BZT55B4V3	4.22	4.3	4.38	5	1	< 1	< 20	1	< 90	< 600	- 0.06	- 0.03
BZT55B4V7	4.6	4.7	4.8	5	1	< 0.5	< 10	1	< 80	< 600	- 0.05	0.02
BZT55B5V1	5	5.1	5.2	5	1	< 0.1	< 2	1	< 60	< 550	- 0.02	0.02
BZT55B5V6	5.48	5.6	5.72	5	1	< 0.1	< 2	1	< 40	< 450	- 0.05	0.05
BZT55B6V2	6.08	6.2	6.32	5	1	< 0.1	< 2	2	< 10	< 200	0.03	0.06
BZT55B6V8	6.66	6.8	6.94	5	1	< 0.1	< 2	3	< 8	< 150	0.03	0.07
BZT55B7V5	7.35	7.5	7.65	5	1	< 0.1	< 2	5	< 7	< 50	0.03	0.07
BZT55B8V2	8.04	8.2	8.36	5	1	< 0.1	< 2	6.2	< 7	< 50	0.03	0.08
BZT55B9V1	8.92	9.1	9.28	5	1	< 0.1	< 2	6.8	< 10	< 50	0.03	0.09
BZT55B10	9.8	10	10.2	5	1	< 0.1	< 2	7.5	< 15	< 70	0.03	0.1
BZT55B11	10.78	11	11.22	5	1	< 0.1	< 2	8.2	< 20	< 70	0.03	0.11
BZT55B12	11.76	12	12.24	5	1	< 0.1	< 2	9.1	< 20	< 90	0.03	0.11
BZT55B13	12.74	13	13.26	5	1	< 0.1	< 2	10	< 26	< 110	0.03	0.11
BZT55B15	14.7	15	15.3	5	1	< 0.1	< 2	11	< 30	< 110	0.03	0.11
BZT55B16	15.7	16	16.3	5	1	< 0.1	< 2	12	< 40	< 170	0.03	0.11
BZT55B18	17.64	18	18.36	5	1	< 0.1	< 2	13	< 50	< 170	0.03	0.11
BZT55B20	19.6	20	20.4	5	1	< 0.1	< 2	15	< 55	< 220	0.03	0.11
BZT55B22	21.55	22	22.45	5	1	< 0.1	< 2	16	< 55	< 220	0.04	0.12
BZT55B24	23.5	24	24.5	5	1	< 0.1	< 2	18	< 80	< 220	0.04	0.12
BZT55B27	26.4	27	27.6	5	1	< 0.1	< 2	20	< 80	< 220	0.04	0.12
BZT55B30	29.4	30	30.6	5	1	< 0.1	< 2	22	< 80	< 220	0.04	0.12
BZT55B33	32.4	33	33.6	5	1	< 0.1	< 2	24	< 80	< 220	0.04	0.12
BZT55B36	35.3	36	36.7	5	1	< 0.1	< 2	27	< 80	< 220	0.04	0.12
BZT55B39	38.2	39	39.8	2.5	1	< 0.1	< 5	30	< 90	< 500	0.04	0.12
BZT55B43	42.1	43	43.9	2.5	0.5	< 0.1	< 5	33	< 90	< 600	0.04	0.12
BZT55B47	46.1	47	47.9	2.5	0.5	< 0.1	< 5	36	< 110	< 700	0.04	0.12
BZT55B51	50	51	52	2.5	0.5	< 0.1	< 10	39	< 125	< 700	0.04	0.12
BZT55B56	54.9	56	57.1	2.5	0.5	< 0.1	< 10	43	< 135	< 1000	0.04	0.12
BZT55B62	60.8	62	63.2	2.5	0.5	< 0.1	< 10	47	< 150	< 1000	0.04	0.12
BZT55B68	66.6	68	69.4	2.5	0.5	< 0.1	< 10	51	< 200	< 1000	0.04	0.12
BZT55B75	73.5	75	76.5	2.5	0.5	< 0.1	< 10	56	< 250	< 1500	0.04	0.12

Notes

- Additional measurement of voltage group 9V1 to 75 at 95 % $V_{zmin.} \leq 35\text{ nA}$ at $T_j 25\text{ }^{\circ}\text{C}$
- (1) $t_p \leq 10\text{ ms}$, $T/t_p > 1000$

BASIC CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

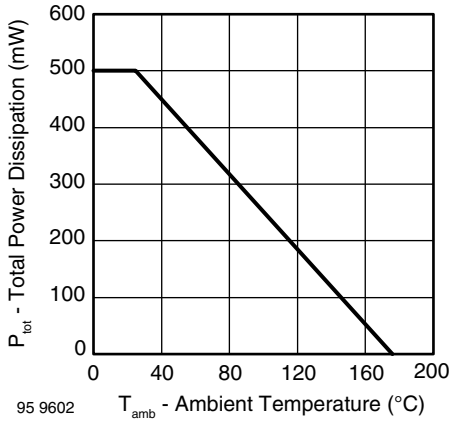


Fig. 1 - Total Power Dissipation vs. Ambient Temperature

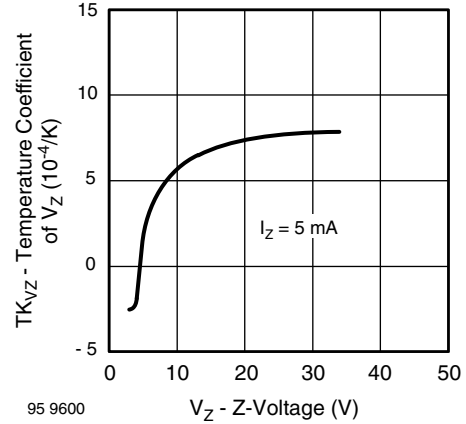


Fig. 4 - Temperature Coefficient of V_Z vs. Z-Voltage

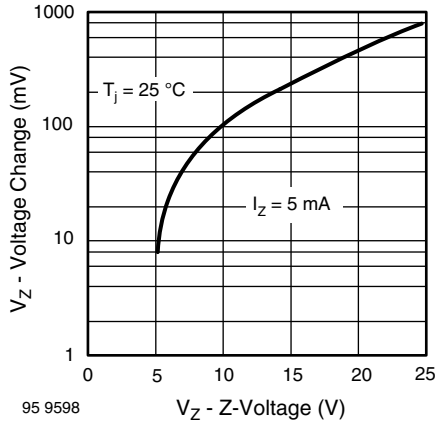


Fig. 2 - Typical Change of Working Voltage under Operating Conditions at $T_{amb}=25\text{ }^{\circ}\text{C}$

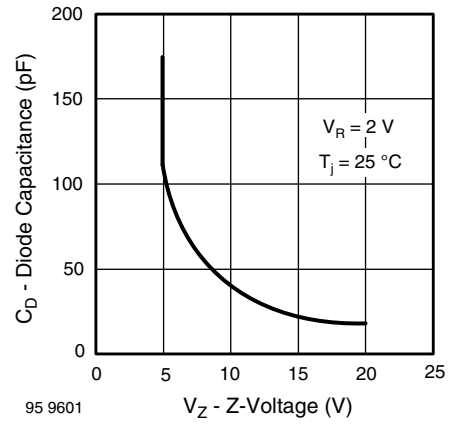


Fig. 5 - Diode Capacitance vs. Z-Voltage

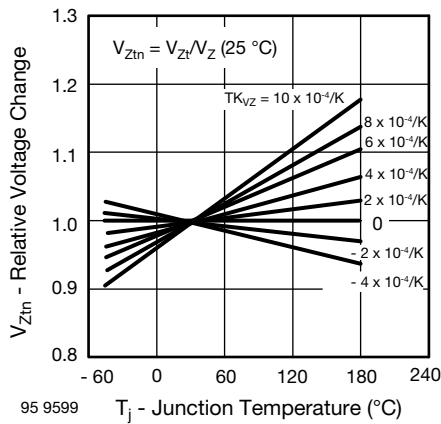


Fig. 3 - Typical Change of Working Voltage vs. Junction Temperature

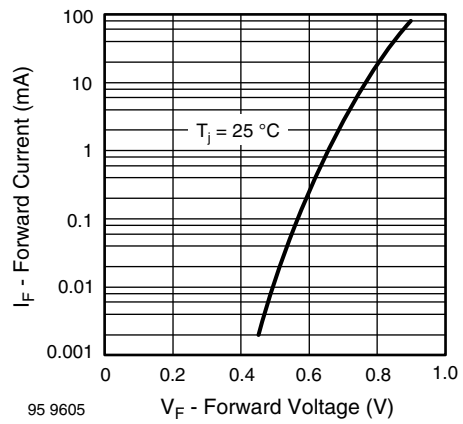


Fig. 6 - Forward Current vs. Forward Voltage

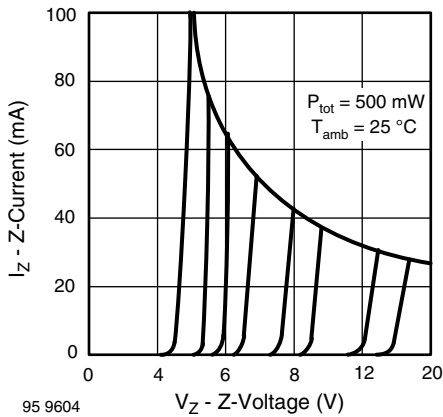


Fig. 7 - Z-Current vs. Z-Voltage

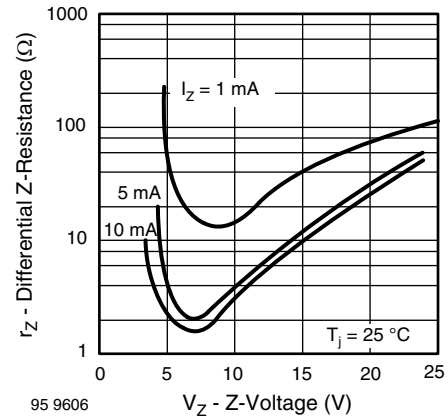


Fig. 9 - Differential Z-Resistance vs. Z-Voltage

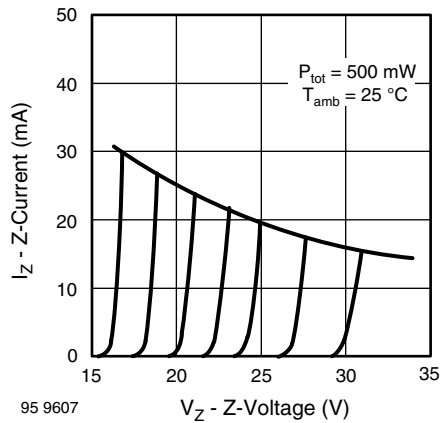


Fig. 8 - Z-Current vs. Z-Voltage

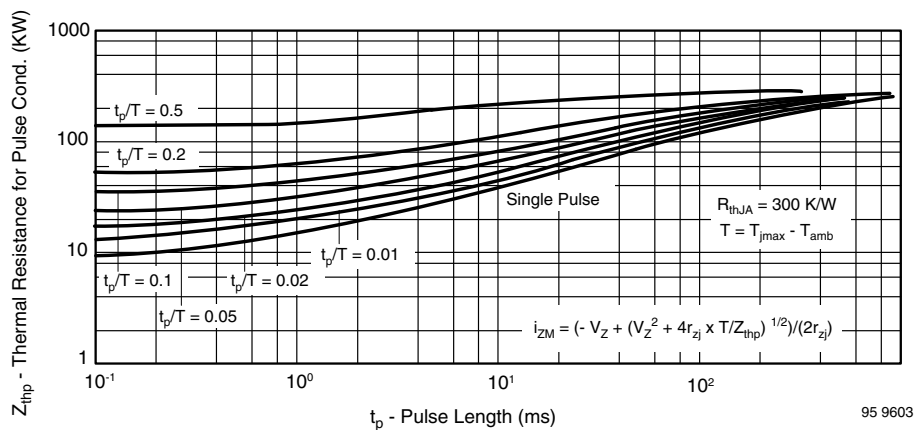
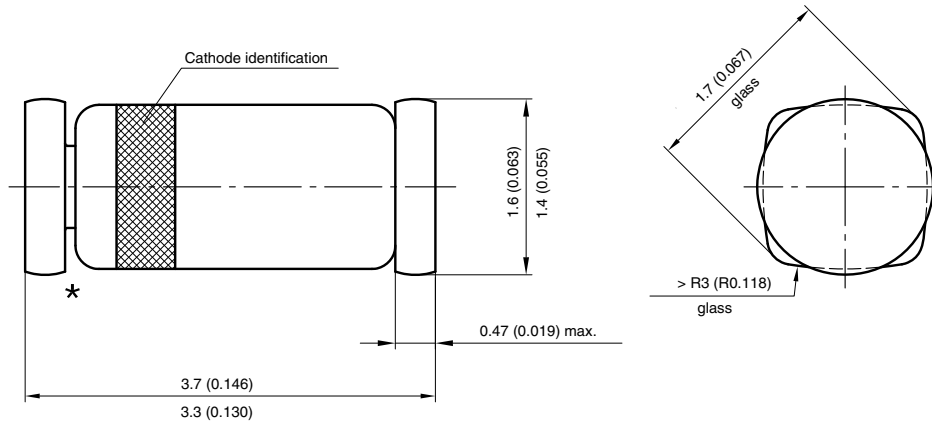


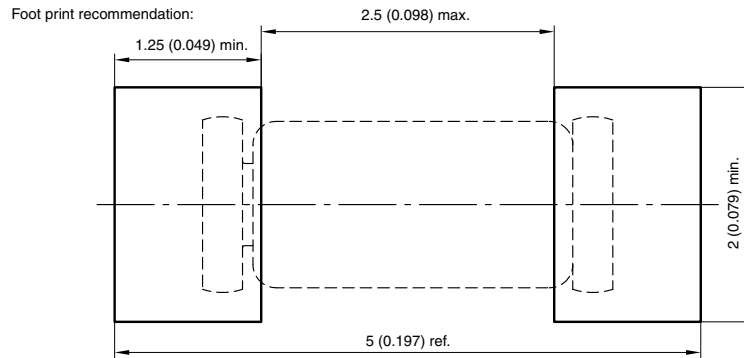
Fig. 10 - Thermal Response



PACKAGE DIMENSIONS in millimeters (inches): **QuadroMELF SOD-80**



* The gap between plug and glass can be either on cathode or anode side



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